





ESP32-S Specification Version V1 Copyright ©2019



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1. Product overview

ESP32-S is a general-purpose WiFi-BT-BLE MCU module with powerful functions and a wide range of uses. It can be used for low-power sensor networks and demanding tasks, such as voice encoding, audio streaming, and MP3 decoding.

The core of this module is the ESP32 chip, which is scalable and adaptive. The two CPU cores can be individually controlled or powered on. The user can cut off the power of the CPU and use the low-power coprocessor to continuously monitor the status changes of the peripherals or whether certain analog quantities exceed the threshold. ESP32 also integrates a wealth of peripherals, including capacitive touch sensors, Hall sensors, low-noise sensor amplifiers, SD card interface, Ethernet interface, high-speed SDIO/SPI, UART, I2S and I2C. The ESP32-S module was developed by Ai-Thinker Technology. The core processor ESP32 of this module has two built-in low-power Xtensa®32-bit LX6 MCUs. The main frequency supports 80 MHz, 160 MHz and 240 MHz.



Appearance size



Characteristics

- ► Ultra-small 802.11b/g/n Wi-Fi + BT SoC module
- > Adopt low-power dual-core 32-bit CPU, can be used as an application processor
- > The main frequency is up to 240MHz, and the computing power is up to 600DMIPS
- Build-in 520KB SRAM
- Support interface of UART/SPI/I2C/PWM/ADC/DAC
- SMD-38 package, convenient for soldering and testing
- Support OpenOCD debugging interface
- > Support multiple sleep modes, the minimum deep sleep current can reach $6.5 \mu A$
- Support STA/AP/STA+AP working mode
- > Support Smart Config/AirKiss one-click network configuration
- General AT commands can be used quickly
- Support serial port local upgrade and remote firmware upgrade (FOTA) embedded Lwip and FreeRTOS



Main parameters

Model	ESP32-S					
Package	SMD-38					
Size	18.0*25.5*3.0 (±0.2)	18.0*25.5*3.0 (±0.2) mm				
Certification	SRCC、FCC、CE、R	oHS				
SPI Flash	Default 32Mbit, maxin	Default 32Mbit, maximum support 128Mbit				
Interface	UART, SPI, SDIO,	UART、SPI、SDIO、I2C、PWM、I2S、IR、ADC、DAC				
ΙΟ	22					
UART rate	Support 300 ~ 4608000	bps, default 115200bps				
Bluetooth	Bluetooth 4.2 BR/EDR	and BLE stander				
Wi-Fi	802.11 b/g/n/e/i					
On-chip sensors	Hall sensor, Temperat	ure sensor, Capacitive touch sensor				
Spectrum range	2412~2484MHz					
Antenna	On-board PCB antenna	/ IPEX				
	802.11b: 17±2 dBm (@	11Mbps)				
Transmit power	802.11g: 14±2 dBm (@	• /				
	802.11n: 13±2 dBm (@					
	CCK, 1 Mbps : -90dBm					
Receiving	CCK, 11 Mbps: -85dBm 6 Mbps (1/2 BPSK): -88dBm					
sensitivity	54 Mbps (3/4 64-QAM					
	MCS7 (65 Mbps, 72.2					
	Active (RF w	• /	21dBm 160~260mA			
		Wi-Fi/BT Tx packet 0dBm	120mA			
		Wi-Fi/BT Rx and listening	80~90mA			
		Associated sleep patterns	0.9mA@DTIM3,			
		(Associated with Light-sleep mode)				
Power		1.2mA@DTIM1 Modem-sleep	CPU is working			
consumption	status	Maximum speed: 20mA				
(typical value)			Normal speed:			
			$5 \sim 10 \text{mA slow}$:			
	T 1 4 1		3mA			
	Light-sleep	-	0.8mA			
	Deep-sleep ULP coprocessor is working 0.5mA Ultra-low power sensor monitoring method25uA@1% duty					
			J .			
		RTC timer + RTC memory	20uA			
Security	Hibernation WPA/WPA2/WPA2-Ei	Only the RTC timer is working	2.5uA			
Security	WIA/WIA2/WIA2-DI					

Table 1.1 main parameters instruction



Power supply range	Supply voltage $3.0V \sim 3.6V$, Supply current >500mA
Operating temperature	-20 °C ~ 85°C
Storage environment	-40 °C ~ 85°C , < 90%RH
Weight	About 1.45g

2.Pin definition

ESP32-S module is connected to 38 interfaces, table 2.1 and table 2.2 is the interface definition.



table 2.1 ESP32-S Pin diagram

GND IO13 SD2 SD2 SD2 SD2 SD2 SD2 SD2 SD2 IO15 IO15 IO2

table 2.2 pin function definition

No.	Pin	Function Description
1	GND	Ground
2	3V3	3.3V power supply(VDD); The output current of the external power supply is recommended to be above 500mA
3	EN	Chip enable terminal, active at high level
4	SENSOR_VP	GPI36,SENSOR_VP,ADC_H,ADC1_CH0,RTC_GPIO0
5	SENSOR_VN	GPI39,SENSOR_VN,ADC1_CH3,ADC_H,RTC_GPIO3
6	IO34	GPI34,ADC1_CH6,RTC_GPIO4
7	1035	GPI35,ADC1_CH7,RTC_GPIO5
8	1032	GPIO32,XTAL_32K_P(32.768kHz crystal oscillator input ADC1_CH4, TOUCH9,RTC_GPIO9
9	1033	GPIO33,XTAL_32K_N(32.768kHz crystal oscillator output ADC1_CH5, TOUCH8,RTC_GPIO8
10	1025	GPIO25,DAC_1,ADC2_CH8,RTC_GPIO6,EMAC_RXD0
11	IO26	GPIO26,DAC_2,ADC2_CH9,RTC_GPIO7,EMAC_RXD1
12	IO27	GPIO27,ADC2_CH7,TOUCH7,RTC_GPIO17,EMAC_RX_DV



13	IO14	CDIO14 ADC2 CHATQUCHADTC CDIO16 MTMS
15	1014	GPIO14,ADC2_CH6,TOUCH6,RTC_GPIO16,MTMS,
		HSPICLK,HS2_CLK,SD_CLK,EMAC_TXD2
14	IO12	GPIO12,ADC2_CH5,TOUCH5,RTC_GPIO15,MTDI,HSPIQ,HS2_DAT A2,SD_DAT A2,EMAC_TXD3
15	GND	Ground
16	IO13	GPIO13,ADC2_CH4,TOUCH4,RTC_GPIO14,MTCK,HSPID,HS2_DA TA3,SD_DAT A3,EMAC_RX_ER
17	SHD/SD2	GPIO9,SD_DATA2,SPIHD,HS1_DATA2,U1RXD
18	SWP/SD3	GPIO10,SD_DATA3,SPIWP,HS1_DATA3,U1TXD
19	SCS/CMD	GPIO11,SD_CMD,SPICS0,HS1_CMD,U1RTS
20	SCK/CLK	GPIO6,SD_CLK,SPICLK,HS1_CLK,U1CTS
21	SDO/SD0	GPIO7,SD_DATA0,SPIQ,HS1_DATA0,U2RTS
22	SDI/SD1	GPIO8,SD_DATA1,SPID,HS1_DATA1,U2CTS
23	1015	GPIO15,ADC2_CH3,TOUCH3,MTDO,HSPICS0,RTC_GPIO13,HS2_C MD,SD_CMD , EMAC_RXD3
24	IO2	GPIO2,ADC2_CH2,TOUCH2,RTC_GPIO12,HSPIWP,HS2_DATA0,SD DATA0
25	IO0	GPIO0,ADC2_CH1,TOUCH1,RTC_GPIO11,CLK_OUT1,EMAC_TX_C LK
26	104	GPIO4,ADC2_CH0,TOUCH0,RTC_GPIO10,HSPIHD,HS2_DATA1, SD_DATA1, EMAC_TX_ER
27	IO16	GPIO16,HS1_DATA4,U2RXD,EMAC_CLK_OUT
28	IO17	GPIO17,HS1_DATA5,U2TXD,EMAC_CLK_OUT_180
29	105	GPIO5,VSPICS0,HS1_DATA6,EMAC_RX_CLK
30	IO18	GPIO18,VSPICLK,HS1_DATA7
31	IO19	GPIO19,VSPIQ,U0CTS,EMAC_TXD0
32	NC	-
33	IO21	GPIO21,VSPIHD,EMAC_TX_EN
34	RXD0	GPIO3,U0RXD,CLK_OUT2
35	TXD0	GPIO1,U0TXD,CLK_OUT3,EMAC_RXD2
36	IO22	GPIO22,VSPIWP,U0RTS,EMAC_TXD1
37	IO23	GPIO23,VSPID,HS1_STROBE
38	GND	Ground



Strapping Pin

Build-in LDO (VDD SDIO)voltage						
Pin	Default	3.3V	3.3V 1.8V			
MTDI/GPIO12	Pull down	0		1		
	System startup method					
Pin	Pin Default SPI Flash startup method Download startup method					
GPIO0	Pull up	1 0				
GPIO2	Pull down	/		0		
During system startup, U0TXD outputs log print information						
Pin	Default	U0TXD flip		U0TXD static		
MTDO/GPIO15	Pull up	1		0		
		SDIO slave signa output tim	-			
Pin	Default	Falling edge input Falling edge output	Falling edge input Rising edge output	Rising edge input Falling edge output	Rising edge input Rising edge output	
MTDO/GPIO15	Pull up	0	0	1	1	
GPIO5	Pull up	0	1	0	1	

Note: ESP32 has a total of 6 strapping pins, software can read the value of these 6 bits in the register "GPIO_STRAPPING". During the chip power-on reset process, the strapping pin samples the level and stores it in the latch, which is latched as "0" or "1", and remains until the chip is powered down or turned off. Each strapping pin is connected to internal pull-up/pull-down. If a strapping pin is not connected or the connected external circuit is in a high impedance state, the internal weak pull-up/pull-down wil determine the default value of the input level of the strapping pin. To change the value of the strapping bit, the user can apply ar external pull-down/pull-up resistor, or use the GPIO of the host MCU to control the level of the strapping pin when the ESP32 is powered on and reset.

After reset, the strapping pin has the same function as the normal pin.

3.Function description

CPU and RAM

ESP32 contains two low-power Xtensa®32-bit LX6 MCUs. On-chip storage includes:

- 448KBytes ROM for program startup and kernel function call
- 520 KB on-chip SRAM for data and instruction storage
- 8KBytes of SRAM in RTC (RTC slow memory) can be accessed by the coprocessor in Deep-sleep mode
- The 8KBytes of SRAM in RTC, that is, RTC fast memory, can be used for data storage and accessed by the main CPU during RTC startup in Deep-sleep mode
- 1kbit EFUSE, of which 256 bits are dedicated to the system (MAC address and chip settings); the remaining 768 bits are reserved for user applications, which include Flash encryption and chip ID

External Flash and SRAM

ESP32 supports up to four 16 MBytes external QSPI Flash and static random access memory (SRAM), and has a hardware encryption function based on AES to protect developers' programs and data.

- ESP32 accesses external QSPI Flash and SRAM through cache. Up to 16 MBytes of external Flash is mapped to the CPU code space, supporting 8-bit, 16-bit and 32-bit access, and executable code
- Up to 8M Bytes of external Flash and SRAM are mapped to the CPU data space, supporting 8-bit, 16bit and 32-bit access. Flash only supports read operations, SRAM can support read and write operations



Supports crystal oscillators with frequencies of 40 MHz, 26 MHz and 24 MHz. The accuracy of the crystal oscillator is between \pm 10 PPM, and the operating temperature range is between -40° C and 85° C. Please select the correct crystal type when using the download tool. In the circuit design, the ground adjustment capacitors C1 and C2 are added to the input and output terminals of the crystal oscillator, respectively. The value of the two capacitors can be flexibly set, ranging from 6 pF to 22 pF. However, the specific capacitance value can only be determined after matching the overall performance of the entire circuit. Generally speaking, if the frequency of the crystal oscillator is 26 MHz, the capacitance values of C1 and C2 are within 10 pF; if the frequency of the crystal oscillator is 40 MHz, the capacitance values of C1 and C2 are 10 pF<C1, C2<22 pF. The frequency of the RTC crystal oscillator is usually 32 kHz or 32.768 kHz. Due to the internal calibration used to correct the frequency offset, the frequency of the crystal oscillator may exceed the range of \pm 20 PPM. When the chip is working in low-power mode, the device should select an external low-speed 32 kHz crystal oscillator clock instead of the internal RC oscillator to obtain an accurate wake-up time.

Power consumption

ESP32 has advanced power management technology that can switch between various power saving modes. Active mode: The chip's radio frequency is in working state. The chip can receive, transmit and listen to signals.

Modem-sleep mode: The CPU keeps running and the clock can be configured. Wi-Fi/Bluetooth baseband and radio frequency are turned off.

Light-sleep mode: The CPU is suspended. RTC and ULP coprocessors run. Any wake-up event (MAC, host, RTC timer or external interrupt) will wake up the chip.

Deep-sleep mode: Only RTC is working. Wi-Fi and Bluetooth connection data are stored in RTC. The ULP coprocessor keeps running.

Hibernation mode: The built-in 8 MHz oscillator and ULP coprocessor are both disabled. RTC memory recovery power is cut off. Only one RTC clock timer on the slow clock and certain RTC GPIOs are active. RTC timer or RTC GPIO can wake up the chip from Hibernation mode.

Associated sleep mode: The power saving mode can be switched between Active mode and Modem-sleep mode/Light-sleep mode. CPU,

Wi-Fi, Bluetooth, and radio frequency are periodically woken up as preset to ensure Wi-Fi/Bluetooth connection.

Ultra-low-power sensor monitoring mode: The main system is in Deep-sleep mode, and the ULP coprocessor is turned on or off periodically to measure sensor data. According to the data measured by the sensor, the ULP coprocessor decides whether to wake up the main system. The power consumption changes with the power saving mode/sleep mode and the working status of the functional module.

4. Electrical parameters

Unless otherwise specified, the test environment for the specifications listed in this chapter is: VBAT= 3.3V, TA= $27^{\circ}C_{\circ}$

Limit parameters:

Rated value	Condition	Value	Unit
Storage	-	-40~85	°C
temperature			
Maximum welding	-	260	°C
temperature			
Supply voltage	IPC/JEDEC J-STD-020	+3.0~+3.6	V

Recommended working conditions:

Working environment	Name	Min	Typical value	Max	Unit
Operating	-	-40	20	85	°C



111							
	temperature						
	Supply voltage	VDD	3.0	3.3	3.6	V	

Digital port characteristics:

Port	Name	Min	Typical value	Max	Unit
Input logic level is low	VIL	-0.3	-	0.25VDD	V
Input logic level is high		0.75VDD	-	VDD+0.3	V
Out put logic level is low	VOL	Ν	-	0.1VDD	V
Output logic level is high		0.8VDD	-	N	V

Wi-Fi RF characteristics:

Description	Min	Typical value	Max	Unit			
		General					
	features						
Input frequency	2412	-	2484	MHz			
Input resistance	-	50	-	Ω			
Input launch	-	-	-10	dB			
PA output power	15.5	16.5	21.5	dBm			
		Sensitivity					
DSSS,1Mbps dBm							
CCK, 11 Mbps	-	-90	-	dBm			
OFDM, 6 Mbps	-	-93	-	dBm			
OFDM, 54 Mbps	-	-75	-	dBm			
HT20, MCSO	-	-93	-	dBm			
HT20, MCS7	-	-73	-	dBm			
HT40, MCSO	-	-90	-	dBm			
HT40, MCS7	-	-70	-	dBm			
MCS32	-	-91	-	dBm			
		Adjacent					
		Channel					
		Suppression					
OFDM, 6 Mbps	-	37	-	dB			
OFDM, 54 Mbps	-	21	-	dB			
HT20, MCS0	-	37	-	dB			
HT20, MCS7	-	20	-	dB			

BLE receiver features:

Parameter	Condition	Min	Typical value	Max	Unit
Sensitivity@ 0.1% BER	-	-	-98	-	dBm
Max received signal@0.1% BER	-	0	-	-	dBm
Co-channel C/I	-	-	+10	-	dB
Adjacent channel	F = F0 + 1 MHz	-	-5	-	dB
selectivity C/I	F = F0 - 1 MHz	-	-5	-	dB
	F = F0 + 2 MHz	-	-25	-	dB
	F = F0 - 2 MHz	-	-35	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB
Out-of-band	30MHz-2000MHz	-10	-	-	dBm
blocking	2000MHz-2400MHz	-27	-	-	dBm

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ESP32-S Wi-Fi+BT SoC module

performance	2500MHz-3000MHz	-27	-	-	dBm
	3000MHz-12.5GHz	-10	-	-	dBm
Intermodulation performance	-	-36	-	-	dBm

BLE transmitter characteristics:

Parameter	Condition	Min	Typical value	Max	Unit
RF transmit frequency	-	-	+7.5	+10	dBm
RF power control range	-	-	25	-	dB
Adjacent channel	F = F0 + 1 MHz	-	-14.6	-	dBm
transmit power	F = F0 - 1 MHz	-	-12.7	-	dBm
	F = F0 + 2 MHz	-	-44.3	-	dBm
	F = F0 - 2 MHz	-	-38.7	-	dBm
	F = F0 + 3 MHz	-	-49.2	-	dBm
	F = F0 - 3 MHz	-	-44.7	-	dBm
	F = F0 + > 3 MHz	-	-50	-	dBm
	F = F0 - 3 MHz	-	-50	-	dBm
Δflavg	-	-	-	265	kHz
Δf2max	-	247	-	-	kHz
Δf2avg/Δf1avg	-	-	-0.92	-	-
ICFT	-	-	-10	-	kHz
Frequency drift rate	-	-	0.7	-	kHz/50us
Frequency drift	-	-	2	-	kHz







6. Application circuit



7. Schematic diagram





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